

### INCHANGE SEMICONDUCTOR

### Isc N-Channel MOSFET Transistor

# **IPB144N12N3G**

#### • FEATURES

- With To-263(D2PAK) package
- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### APPLICATIONS

Switching applications

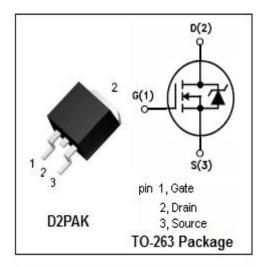
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)								
SYMBOL	PARAMETER	VALUE	UNIT					
V <sub>DSS</sub>	Drain-Source Voltage	120	V					
V <sub>GSS</sub>	Gate-Source Voltage	±20	∧v					
ID	Drain Current-ContinuousTc=25℃ Tc=100℃	56 41	A					
I <sub>DM</sub>	Drain Current-Single Pulsed	224	А					
PD	Total Dissipation @T <sub>C</sub> =25°C	300	W					
T <sub>ch</sub>	Max. Operating Junction Temperature	175	°C					
T <sub>stg</sub>	Storage Temperature	-55~175	°C					

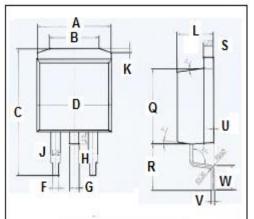
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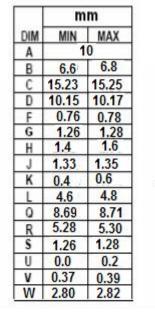
#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance		°C <b>/W</b>	
Rth(ch-a)	h(ch-a) Channel-to-ambient thermal resistance		°C/W	

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#### **ELECTRICAL CHARACTERISTICS**

 $T_{\text{C}}\text{=}25^\circ\!\!\mathbb{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 1mA	120			V
V <sub>GS</sub> (th)	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =0.27mA	2.0		4.0	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =56A		12.3	14.4	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> =0V			±0.1	μA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =100V; V <sub>GS</sub> = 0V;Tj=25℃ V <sub>DS</sub> =100V; V <sub>GS</sub> = 0V;Tj=125℃			1 100	μA
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =56A, V <sub>GS</sub> = 0 V		1.0	1.2	V

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